imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Preferred Device

Silicon Controlled Rectifiers Reverse Blocking Thyristors

Designed primarily for half-wave ac control applications, such as motor controls, heating controls and power supplies.

Features

- Glass Passivated Junctions with Center Gate Geometry for Greater Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Construction for Low Thermal Resistance, High Heat Dissipation and Durability
- Blocking Voltage to 800 V
- Pb-Free Packages are Available*

MAXIMUM RATINGS[†] (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
$\begin{array}{l} \mbox{Peak Repetitive Off-State Voltage (Note 1)} \\ (T_J = -40 \mbox{ to } 125^{\circ}\mbox{C}, \mbox{Sine Wave}, \\ 50 \mbox{ to } 60 \mbox{ Hz}, \mbox{ Gate Open}) & 2N6394 \\ & 2N6395 \\ & 2N6397 \\ & 2N6399 \end{array}$	V _{DRM,} V _{RRM}	50 100 400 800	V
On-State RMS Current (180° Conduction Angles; T _C = 90°C)	I _{T(RMS)}	12	A
Peak Non-Repetitive Surge Current (1/2 Cycle, Sine Wave, 60 Hz, T _J = 90°C)	I _{TSM}	100	A
Circuit Fusing (t = 8.3 ms)	l ² t	40	A ² s
Forward Peak Gate Power (Pulse Width \leq 1.0 μ s, T _C = 90°C)	P _{GM}	20	W
Forward Average Gate Power (t = 8.3 ms, T_C = 90°C)	P _{G(AV)}	0.5	W
Forward Peak Gate Current (Pulse Width \leq 1.0 μ s, T _C = 90°C)	I _{GM}	2.0	A
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C

MAXIMUM RATINGS[†] (T_J = 25°C unless otherwise noted)

Rating	Symbol	Мах	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.0	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	ΤL	260	°C

†Indicates JEDEC Registered Data

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

 V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

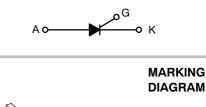
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

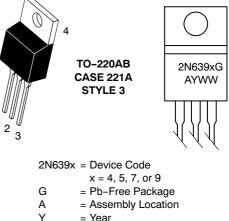


ON Semiconductor®

http://onsemi.com

SCRs 12 AMPERES RMS 50 thru 800 VOLTS





WW = Work Week

PIN ASSIGNMENT			
1	Cathode		
2	Anode		
3	Gate		
4	Anode		

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•				
	I _{DRM} , I _{RRM}	-	-	10 2.0	μA mA
ON CHARACTERISTICS			ļ		
†Peak Forward On-State Voltage (Note 2) (I _{TM} = 24 A Peak)	V _{TM}	-	1.7	2.2	V
†Gate Trigger Current (Continuous dc) (V_D = 12 Vdc, R_L = 100 Ohms)	I _{GT}	-	5.0	30	mA
†Gate Trigger Voltage (Continuous dc) (V_D = 12 Vdc, R_L = 100 Ohms)	V _{GT}	-	0.7	1.5	V
Gate Non-Trigger Voltage (V _D = 12 Vdc, R _L = 100 Ohms, T _J = 125°C)	V _{GD}	0.2	-	-	V
† Holding Current (V_D = 12 Vdc, Initiating Current = 200 mA, Gate Open)	I _Н	-	6.0	50	mA
Turn-On Time (I_{TM} = 12 A, I_{GT} = 40 mAdc, V_D = Rated V_{DRM})	t _{gt}	-	1.0	2.0	μs
Turn-Off Time (V _D = Rated V _{DRM}) $(I_{TM} = 12 \text{ A}, I_R = 12 \text{ A})$ $(I_{TM} = 12 \text{ A}, I_R = 12 \text{ A}, T_J = 125^{\circ}\text{C})$	tq		15 35		μs
DYNAMIC CHARACTERISTICS		•	-	•	
Critical Rate-of-Rise of Off-State Voltage Exponential	dv/dt	_	50	-	V/us

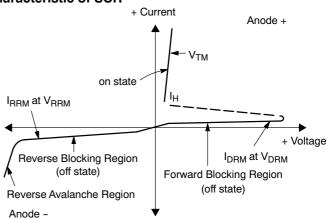
 $(V_D = Rated V_{DRM}, T_J = 125^{\circ}C)$

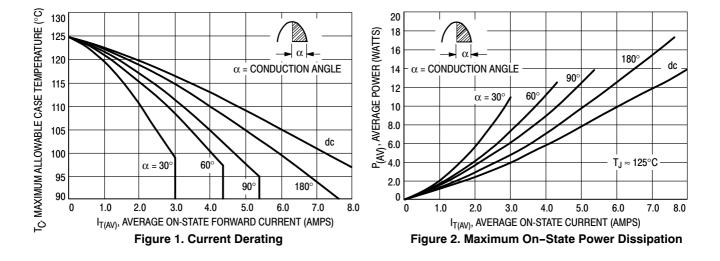
†Indicates JEDEC Registered Data

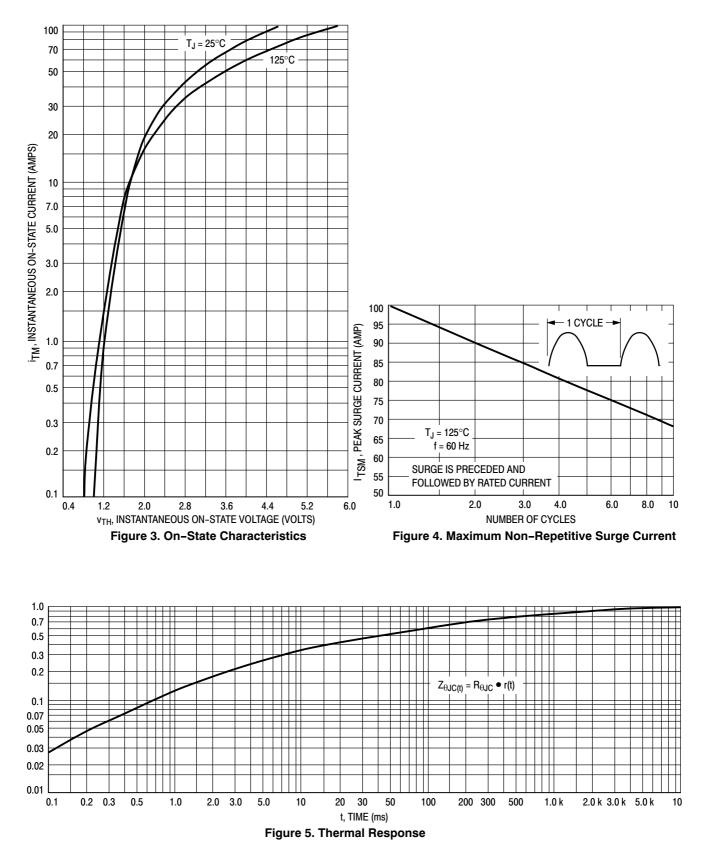
2. Pulse Test: Pulse Width \leq 300 µsec, Duty Cycle \leq 2%.

Voltage Current Characteristic of SCR

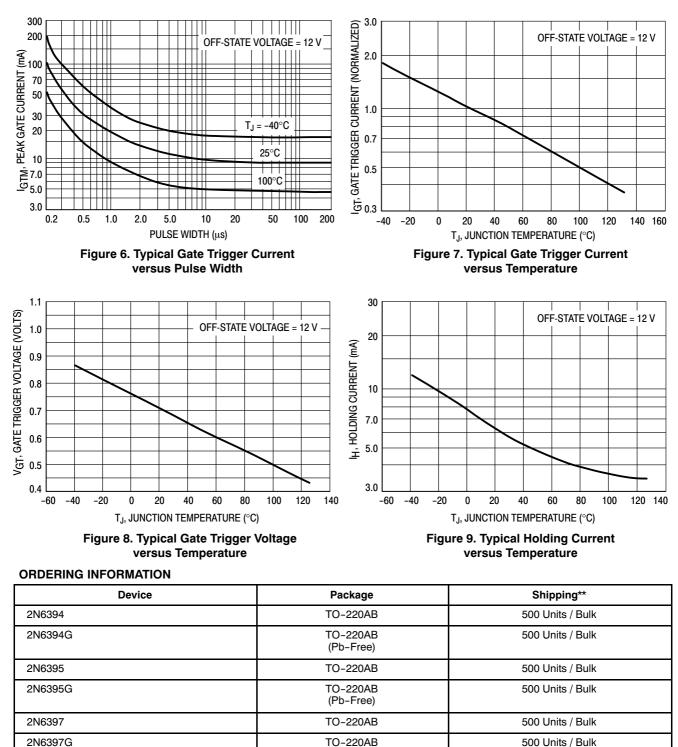
Symbol	Parameter
V _{DRM}	Peak Repetitive Off State Forward Voltage
I _{DRM}	Peak Forward Blocking Current
V _{RRM}	Peak Repetitive Off State Reverse Voltage
I _{RRM}	Peak Reverse Blocking Current
V _{TM}	Peak On State Voltage
I _H	Holding Current







TYPICAL CHARACTERISTICS



**For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

(Pb-Free)

TO-220AB

TO-220AB

(Pb-Free)

TO-220AB

(Pb-Free)

500 Units / Bulk

500 Units / Bulk

50 Units / Rail

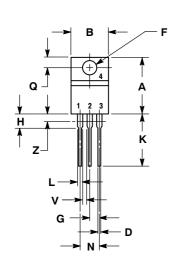
2N6399

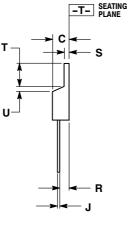
2N6399G

2N6399TG

PACKAGE DIMENSIONS

TO-220AB CASE 221A-07 **ISSUE AA**





NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14 5M 1982

2. CONTROLLING DIMENSION: INCH. 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED

	INCHES		MILLIMETER	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Η	0.110	0.155	2.80	3.93
J	0.014	0.022	0.36	0.55
Κ	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
Ν	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
۷	0.045		1.15	
Ζ		0.080		2.04

STYLE 3: PIN 1. CATHODE

2. ANODE

3. GATE

ANODE 4

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